## NSN 5961-01-485-0921

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Inclosure Material:	
Plastic	
Overall Length:	
Between 0.157 inches and	I 0.177 inches
Overall Width:	
Between 0.100 inches and	I 0.110 inches
End Application:	
Flight simulator	
Special Features:	
Device marking code ug;	maximum repetitive peak reverse voltage 400; maximum rms voltage 280; maximum dc blocking voltage 400;
maximum average forward	d rectified current at tl =100 degrees c 1.0; peak forward surge current 8.3 ms single half sine-wave superimposed
on rated load 30; operating	g and storage temp range m55.0 to 150.0
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	